NSN 5961-01-369-9102

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Inclosure Material:

Metal

Overall Length:

Between 6.4 millimeters and 11.4 millimeters

Overall Diameter:

22.2 millimeters

Mounting Facility Quantity:

2

Internal Configuration:

Field effect

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-204aa

Electrode Internally-electrically Connected To Case:

Drain

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-120.0 drain to source voltage and -120.0 drain to gate voltage

Current Rating Per Characteristic:

5.00 amperes drain current

Power Rating Per Characteristic:

75.0 watts total power dissipation

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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